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OPEN Unusual bidirectional frequency dependence of dynamical susceptibility in hexagonal intermetallic Pr₂Ni_{0.95}Si_{2.95}

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In this study, the synthesis of a novel ternary intermetallic compound Pr₂Ni_{0.95}Si_{2.95} forming in single phase only by deliberately introducing vacancies in Ni/Si site is reported. The detailed studies on dc magnetization, heat capacity, ac magnetization & associated dynamical scaling, different types of non-equilibrium dynamical behaviour, viz., magnetic relaxation behaviour as a function of wait time and temperature, aging phenomena, and magnetic memory effect firmly establish that the compound exhibits spin freezing behaviour below 3.3 K (T₆). However, below T₆, temperature dependence of ac susceptibility data exhibit an additional peak that shows reverse frequency dependence to that generally observed in a glassy system. The unusual bidirectional frequency dependence in a single magnetic system is of significant interest and rarely reported in literature. Competing exchange interaction arising from $c/a \sim 1$ and crystallographic randomness driven magnetic phase separation has been argued to be responsible for such observation. The reverse frequency shift of the low temperature peak has been described on the basis of a simple phenomenological model proposed in this work.

A correlated magnetic spin system is called magnetically frustrated when it is unable to simultaneously minimize all its interaction energies between it's ground state configuration of spins. Magnetically frustrated systems are rich in physics and one of the central themes in condensed-matter physics research not only from fundamental point of view, but also for application purposes. Frustration can have different origins in a magnetic system, e.g., favourable lattice geometry, competing magnetic interactions. In the presence of disorder such frustrated systems may often drive to a spin freezing state below a typical temperature, called spin freezing temperature. In these systems, presence of random magnetic anisotropy often offer a breeding ground for several unconventional physical properties¹⁻⁷.

During the last few years, ternary silicide intermetallic compounds of R_2 TSi₃ type, with R = rare-earth element and T = transition metal, have attracted much attention due to their highly interesting magnetic properties. Most of the R_2 TSi₃ type of compounds crystallizes in hexagonal AlB₂ type crystal structure with space group $P6/mmm^8$. The rare-earth (R) ions sit on the Al site symmetry (Wyckoff 1a) forming triangles of nearest neighbour, while the T and Si atoms are randomly distributed (Wyckoff 2d) between two hexagonal layers (made by edge sharing triangles of rare-earths). Thus, the crystal structure consists of hexagonal rare-earth atoms layer and randomly distributed T-Si layer along the hexagonal c-axis (Fig. 1). In these type of compounds, geometrical frustration^{1,9,10} can arises due to the presence of antiferromagnetic interaction in the hexagonal crystal structure between *R* ions. Additionally, in R_2 TSi₃ type of compounds, the lattice parameters a and c values are comparable yielding $c/a \sim 1$, i.e., nearest-neighbour (NN) and next-nearest-neighbour (NNN) exchange interactions (J) are comparable and a strong frustration occurs when $J_{\rm NN}$ and $J_{\rm NNN}$ are of opposite sign. Quite a few members of this type exhibit magnetically frustrated spin-glass behaviour due to competing magnetic interactions^{5,11-15}. On the other hand T and Si ions are randomly distributed between the two hexagonal layers comprising rare-earth ions, that causes variation in local environment between the rare-earth ions. This type of variation of the electronic environment

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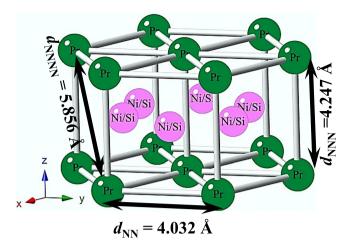


Figure 1. Crystal structure of Pr₂Ni_{0.95}Si_{2.95}.

between the rare earth ions are favourable for the coexistence of magnetically different phases in a crystallographically single phase compound. A considerable number of such magnetic phase separated systems exhibit glassy behaviour. The glassiness in such a phase-separated system can have two likely origins: first, the slow dynamics of the coexisting phases due to their metastability, and secondly, the frustration arising from the magnetic interaction between two clusters having a distinctly different magnetic nature.

Among the R_2NiSi_3 family, it is reported that Gd_2NiSi_3 and Er_2NiSi_3 exhibit spin glass state coupled with AFM type ordering⁵. However, $Ho_2Ni_{0.95}Si_{2.95}$ is a highly frustrated magnetic system consisting of very weakly correlated FM clusters, the correlation of which extends up to only 10-12 unit cells⁶. The correlation between the FM clusters is so weak that any glassy state formation is forbidden in this system. In this present work, we report the successful synthesis of a novel intermetallic compound $Pr_2Ni_{0.95}Si_{2.95}$, which form in single phase only with defect crystal structure. The compound undergoes spin cluster glass behaviour below 3.3 K. The main interest in this material stems from the fact that unusual coexistence of opposite frequency shift of the transition temperatures has been observed for this compound, which is rather hard to find in nature. Randomness driven phase segregation has been argued to be responsible for such unique observation. A simple phenomenological model is proposed that reproduces the main features of this unexpected observation qualitatively.

Results and Discussion

The room temperature XRD pattern of the stoichiometric Pr₂NiSi₃ is shown in Fig. 2(a). As seen from the figure, around the (101) reflection of Pr₂NiSi₃ phase, minor contributions of additional phases can also be observed (~6% of main phase). On the basis of detailed analysis using PDXL software package, it is determined that the additional phases belong to PrNiSi2 type of stoichiometry in addition to another minor contribution from Pr metal. It may be noted here that although many similar R_2TX_3 type of compounds have been reported in literature to form along with a secondary phase which were of RT₂X₂ type¹⁶, in contrast to PrNiSi₂ found in our system. We had earlier reported similar RNiSi₂ type of secondary phase in R_2 NiSi₃ (R = Ho, Tm) compounds^{6,17}. These additional XRD peaks, however, can not be removed by thermal annealing as the single phase compounds could be synthesized only by deliberately tweaking the proportion of initial stoichiometry by subtracting the volume fraction of elements present in the secondary phase. After the first attempt, the volume fraction of the secondary phase got drastically reduced and continuing similar steps iteratively single phase XRD pattern is finally achieved. The single phase compound thus could be synthesized only by introducing defects in Ni and Si sites having the starting composition Pr₂Ni_{0.95}Si_{2.95} where all the peaks in the XRD pattern can be well indexed with space group P6/mmm [Fig. 2(b)]. The refined stoichiometry from the Rietveld refinement using FULLPROF software¹⁸ agrees well with the starting composition of the compound. The different crystallographic parameters estimated from the full-Rietveld analysis are summarized in Table 1. One may find that, $c/a \simeq 1.05$, suggesting that NN and NNN distances between the magnetic Pr ions are close enough. Furthermore, the scanning electron microscopy (SEM) measurements were carried out in both Back-scatter electron detector (BSE) mode and secondary electrons (SE) mode (tomographic mode) to check the homogeneity of the sample (Fig. 2(c-e)). The uniform chemical contrast of BSE signal confirms the phase homogeneity of the sample. The SEM and energy dispersive X-ray spectroscopy (EDX) reveals an essentially single phase nature of the compound with average composition Pr₂Ni_{0.89}Si_{2.99} that is in good agreement with that obtained from Rietveld refinement (Fig. 2(c-h)). Transmission Electron Microscopy (TEM) was also carried out to investigate the nature of phase, composition and crystallinity of intermetallic compound Pr₂Ni_{0.95}Si_{2.95}. Figure 3(a) represents the TEM image of one grain of the compound. The selected area electron diffraction (SAED) pattern from a region marked by a dotted circle is shown in Fig. 3(b), which indicates the single crystalline nature of the material. Measurement was carried out on several grains to confirm the single crystalline nature. SAED was indexed using the lattice parameters of hexagonal crystal structure (lattice parameters, a = 4.032 Å and c = 4.247 Å). Though some of the earlier reports yield superstructure formation in single crystalline R_2 TSi₃ type of materials¹⁹, no evidence of any such superstructure formation could be traced from the electron diffraction pattern in the defect structure compound Pr₂Ni_{0.95}Si_{2.95} [Fig. 3(b)]. The HRTEM image in Fig. 3(c) from a dotted red box region again clearly showing the single crystalline phase. To investigate the

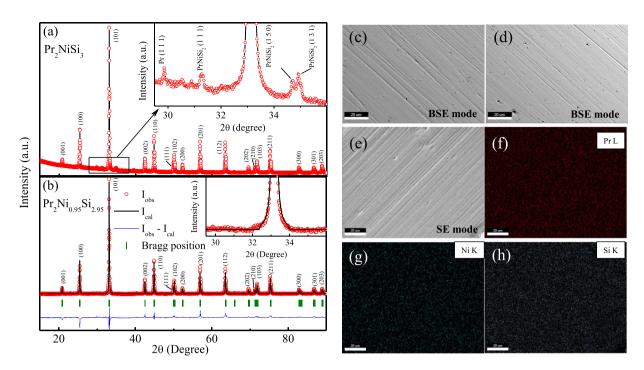


Figure 2. Room temperature powder XRD pattern of (a) Pr_2NiSi_3 and (b) $Pr_2Ni_{0.95}Si_{2.95}$ along with full Rietveld refinement. Inset shows the presence of secondary phases of Pr and $PrNiSi_2$ type in Pr_2NiSi_3 (upper), while $Pr_2Ni_{0.95}Si_{2.95}$ (lower) form in single phase. SEM image in (c,d) BSE mode in two different regions and in (e) SE mode (tomography). (f-h) Elemental mapping by SEM equipped with EDX on the surface of $Pr_2Ni_{0.95}Si_{2.95}$ from the region presented in (e).

Compound		Pr ₂ N	Pr ₂ Ni _{0.95} Si _{2:95}							
Space group		P6/n	P6/mmm, (No. 191)							
Lattice parameters										
a(Å)		4.032	4.032							
c(Å)		4.247	4.247							
Cell Volume, V _{cell} (Å ³)		59.83	59.831(3)							
R_f		6.8	6.8							
R_{Bragg}		9.2	9.2							
Atomic positions										
Atom	Wyckoff Symbol	x	y	z	occ. parameter*	site occupancy × 100%				
Pr	1 <i>a</i>	0	0	0	0.0416	100				
Ni	2 <i>d</i>	1/3	2/3	1/2	0.0197(1)	23.65 (10)				
Si	2d	1/3	2/3	1/2	0.0614(1)	73.68 (10)				

Table 1. The estimated crystallographic parameters from the full-Rietveld analysis of powder x-ray diffraction data of $Pr_2Ni_{0.95}Si_{2.95}$ taken at room temperature. *occ. parameter = site multiplicity/highest multiplicity of space group.

chemical composition of the compound, we have performed energy dispersive X-ray spectroscopy (EDX) in high-angle annular dark field (HAADF) scanning transmission electron microscopy (STEM-HAADF) mode. Figure 3(d) shows the STEM-HAADF image, and Fig. 3(e) showing EDX spectrum indicating the presence of Pr, Ni and Si. The observed Cu and C signal is due to the C-coated Cu grid. For a detailed distribution of atomic content inside the nanocrystals, elemental mapping of Pr, Ni and Si was performed using drift corrected EDX spectrum imaging using STEM-HAADF mode. The STEM-HAADF image in Fig. 3(d) and the corresponding chemical maps from orange boxed region for Pr, Ni and Si acquired using Pr-L, Ni-K and Si-K energy and overlay of three images are presented in Fig. 3(f), respectively. EDX maps were collected while beam of about 2 nm was scanning across the marked area. In this process X-rays were collected point by point from 50 points in x-direction and 25 points in y-direction from the STEM-HAADF image shown in Fig. 3(d). Composite maps of Pr, Ni and Si were presented in Fig. 3(f) confirm the single phase nature of the material with stoichiometry Pr, Ni_{0.97}Si_{2.89}.

The low temperature XRD measurements have also been carried out for the synthesized compound to investigate the evolution of crystal structure with temperature. Figure 4 shows the XRD patterns measured at different temperatures in the temperature region 15–300 K for Pr₂Ni_{0.95}Si_{2.95}. The low temperature XRD patterns reveal that

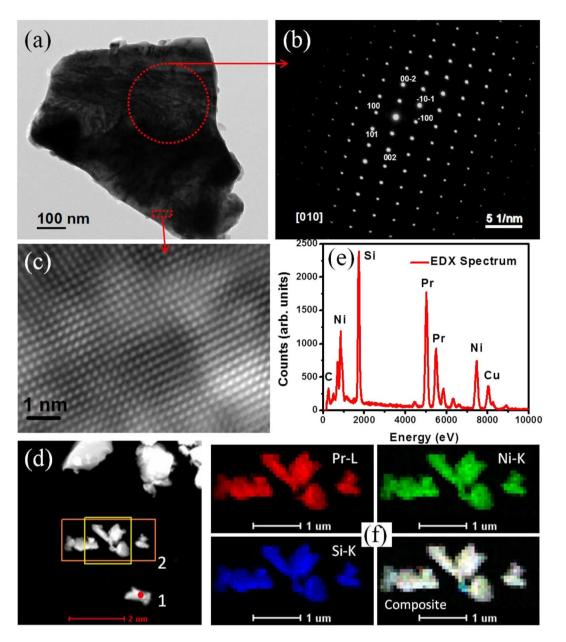


Figure 3. (a) Low magnification bright-field TEM image, (b) Selected area electron diffraction pattern from the circular area in (a), (c) High resolution TEM image from the rectangular area in (a), (d) STEM-HAADF image, (e) EDX spectrum from area 1 in (e), (f) EDX elemental maps and overlay of different elements.

crystal structure remains conserved down to 15 K. The temperature evolution of the estimated unit cell volume has been analysed using the relation,

$$V(T) = \gamma U(T)/K_0 + V_0 \tag{1}$$

where, V_0 is the unit cell volume at zero temperature limit, K_0 is the bulk modulus of the system and γ is the Grüneisen parameter. According to Dbye approximation, the internal energy, U(T), can be expressed as,

$$U(T) = 9Nk_B T \left(\frac{T}{\Theta_D}\right)^3 \int_0^{\frac{\Theta_D}{T}} \frac{x^3}{e^x - 1} dx$$
 (2)

with N is the total number of atoms per unit cell and $x = \frac{\hbar \omega}{k_B T}$. Using this approximation, Debye temperatures for the compound found to be 300 ± 10 K, which suggests quite a strong spin-orbit interaction (higher phonon energy mode) in the system (inset: Fig. 4). This value of Θ_D founds to be similar to that estimated for some other rare-earth analogues of the same family⁵.

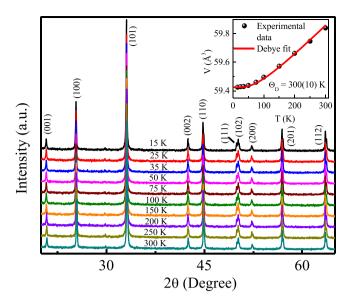


Figure 4. Observed powder XRD profiles of $Pr_2Ni_{0.95}Si_{2.95}$ measured at various temperatures between 15 and 300 K. Inset shows the temperature evolution of the unit-cell volume along with fit to Eq. 1. Error bars are within the symbol size limit.

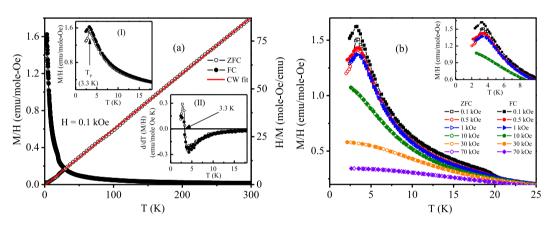


Figure 5. (a) ZFC and FC dc magnetization (M/H) (left panel) and inverse ZFC magnetic susceptibility (H/M) (right panel) as a function of temperature for $Pr_2Ni_{0.95}Si_{2.95}$ at an applied magnetic field of 0.1 kOe. Inset (I): expanded low temperature region of ZFC and FC magnetic susceptibility. Inset (II) shows temperature derivative of ZFC and FC susceptibility as a function of temperature. (b) M/H(T) for different applied magnetic fields. Inset shows expanded low temperature region.

The dc magnetic susceptibility (M/H) as a function of temperature measured in zero-field-cooled (ZFC) and field-cooled (FC) modes for $Pr_2Ni_{0.95}Si_{2.95}$ under a field of 0.1 kOe are shown in Fig. 5(a). In both the measurements, a maxima is observed at the peak temperature $T_p = 3.3$ K. Temperature derivative of the magnetization change their sign at the peak temperature, which is commonly considered as a signature of antiferromagnetic ordering [Inset (II): Fig. 5(a)]. At low temperature, $\chi_{ZFC}(T)$ and $\chi_{FC}(T)$ bifurcates from each other suggesting the presence of irreversibility (magnetic metastability) in the system²⁰. At higher applied field strength, the extent of bifurcation decreases and the peak becomes broader. For applied field $H \ge 10$ kOe, $\chi_{ZFC}(T)$ and $\chi_{FC}(T)$ coincide with each other and the peak disappears with the exhibition of ferromagnetic type behaviour [Fig. 5(b)]. The temperature dependence of inverse susceptibility deviates from linear Curie-Weiss (CW) behaviour below 35 K, either due to the presence of crystalline electric field (CEF) effect or the presence of short range magnetic correlations up to such higher temperature, which is almost 10 times higher than the peak temperature [right panel: Fig. 5(a)]. The CW fit of inverse susceptibility in the temperature region 35–300 K yield a positive paramagnetic Curie-Weiss temperature, $\theta_p = 0.5$ K, suggesting the presence of considerable ferromagnetic interaction in this system. The calculated paramagnetic effective moment (μ_{eff}) is found to be 3.66 μ_B /Pr-ion which is close to theoretical paramagnetic free moment value of Pr^{3+} ion (3.58 μ_B).

The field dependence of isothermal magnetization at different temperatures are shown in Fig. 6(a). The M(H) behaviour at the lowest temperature (2 K) is linear upto applied magnetic field of 7.5 kOe [Fig. 6(b)], while at higher applied field it tends to saturate. Despite the application of a strong magnetic field of $70 \, \text{kOe}$, full saturation

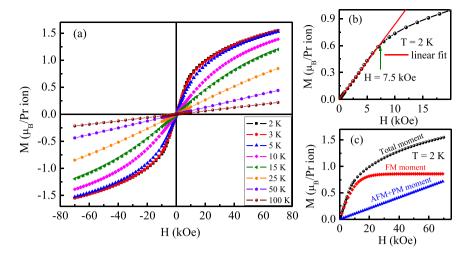


Figure 6. (a) Field dependence of isothermal magnetization for $Pr_2Ni_{0.95}Si_{2.95}$ at different temperatures. (b) M(H) at T = 2 K along with linear fitted region. (c) M(H) at T = 2 K along with extracted different types of magnetic volume fraction using Eq. 3.

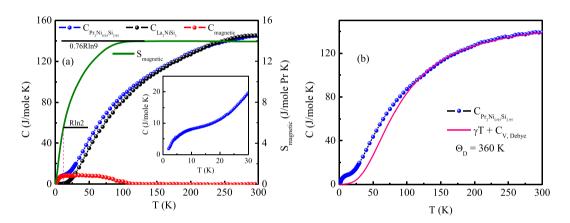


Figure 7. (a) Zero field heat capacity of $Pr_2Ni_{0.95}Si_{2.95}$, La_2NiSi_3 , magnetic contribution of heat capacity (left panel) and magnetic entropy (right panel) as a function of temperature. Inset shows expanded low temperature region of heat capacity for $Pr_2Ni_{0.95}Si_{2.95}$. (b) Heat capacity data is fitted to Debye model according to Eq. 4.

behaviour of the magnetization could not be obtained. The value of the magnetic moment at 2 K for 70 kOe applied field is $1.55\,\mu_{\rm B}$ /Pr-ion, which is less than the expected saturation moment value for parallel spin configuration of Pr³+ ($gJ=3.2\,\mu_{\rm B}$, with g=4/5, J=4) moments. No magnetic hysteresis is observed down to 2 K. The M(H) is not linear even at T = 25 K, which is in the same line with the observation that the inverse susceptibility deviates from linear behaviour below 35 K. At further higher temperatures, however, M(H) behaviour found to be linear, similar to that expected in a paramagnetic system. The field dependence of magnetic isotherms can be analysed considering a combined effect of ferromagnetic and antiferromagnetic and(or) paramagnetic isotherms by the equation,

$$M(H) = A[\tanh(BH)] + CH \tag{3}$$

where *A*, *B* and *C* are fitting parameters. A significant amount of ferromagnetic moment volume fraction is evidenced along with linear (combined antiferromagnetic and paramagnetic) moment volume fraction for the compound [Fig. 6(c)].

The specific heat data measured under relaxation technique of $Pr_2Ni_{0.95}Si_{2.95}$ and the nonmagnetic reference compound La_2NiSi_3 are shown in Fig. 7(a). Corresponding to the peak (T_p) in dc magnetic susceptibility data, we do not observe any sharp anomaly near 3.3 K that can indicate a magnetic phase transition. Instead, C(T) of $Pr_2Ni_{0.95}Si_{2.95}$ shows a very broad anomaly in the temperature range 2–15 K. The absence of sharp peak around $T_p = 3.3$ K suggest the possible absence of any long range AFM order, that was observed earlier in some other members of this family⁵. Further, we have found that the specific heat attains a saturation value (145.5 J/mole-K) at room temperature which is close to the expected classical Dulong-Petit value of C = 3 nR = 17.7 R = 147.1 J/mole-K for this compound. The magnetic contribution $(C_{magnetic})$ of heat capacity also shows a broad hump over a quite wide temperature range, which may be ascribed to either Schottky-type anomaly originating from crystalline electric field (CEF) or the presence of short range magnetic interaction in this temperature range. The

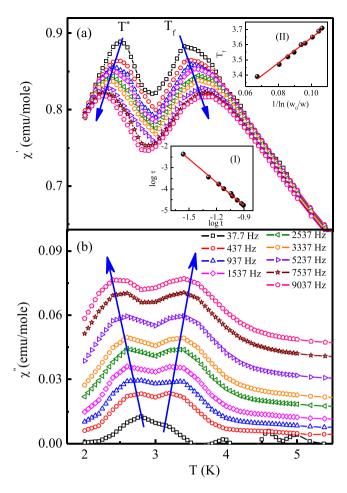


Figure 8. (a) The real part of ac magnetic susceptibility of $Pr_2Ni_{0.95}Si_{2.95}$ as a function of temperature at different frequencies. Inset (I) shows the critical slowing down behaviour of freezing temperature, where $t = (T_f - T_{SG}/T_{SG})$. Inset (II) shows the variation of freezing temperature, T_p , as a function of $ln(\nu_0/\nu)$. The solid line shows the fit to Vogel-Fulcher law. (b) The imaginary part of ac magnetic susceptibility of $Pr_2Ni_{0.95}Si_{2.95}$ as a function of temperature at different frequencies.

calculated magnetic entropy value at $T_P (= 3.3 \text{ K})$ reaches 0.17 R J/mole-Pr-K which is only about 24% of Rln2, where Rln2 being the minimum entropy required for a spin doublet ground state. The estimated magnetic entropy thus appears to be rather small for the occurrence of any true long-range magnetic ordering around the phase transition temperature, T_P The magnetic entropy saturates at much higher temperature (T > 100 K) with the value 13.95 J/mole-Pr-K (0.76 Rln9), which is lower than that expected for trivalent Pr-ion [Rln(2J + 1) = Rln9, with J = 4]. This may be due to CEF effect or presence of short-range magnetic correlations up to such higher temperature. In the temperature range 110–300 K, the specific heat behaviour can be fitted by

$$C(T) = \gamma T + nC_{V,Debye}(T) \tag{4}$$

where, the coefficient γ is usually due to the electronic contribution (Sommerfeld coefficient), n is the number of atoms per formula unit (here we have taken n = 5.9) and C_{VDebye} is the lattice heat capacity contribution owing to acoustic phonon at constant volume. Debye heat capacity per mole is expressed as,

$$C_{V,Debye} = 9R \left(\frac{T}{\Theta_D}\right)^3 \int_0^{\Theta_D/T} \frac{x^4 e^x}{(e^x - 1)^2} dx$$
 (5)

This is an accurate analytic Padé approximation function of T/Θ_D . The estimated Debye temperature (Θ_D) founds to be 360 K [Fig. 7(b)], which is slightly higher to that estimated from the temperature evolution of unit cell volume data. The low temperature mismatch of the fit arises due to the CEF contribution in addition to possible short range magnetic correlations, which are not taken care by the above analysis of specific heat.

Since short range magnetic correlations can be probed through most sensitive technique of ac susceptibility measurement²¹, we have carried out dynamical susceptibility measurements. The temperature dependence of real part (χ') and imaginary part (χ'') of ac susceptibility at different frequencies for $Pr_2Ni_{0.95}Si_{2.95}$ is shown in Fig. 8(a,b), respectively. As seen from the figure, close to the peak temperature ($T_p = 3.3$ K) determined from dc magnetization data, a peak is observed that is very sensitive to applied frequency. The peak temperature shifts

to higher temperature region with increase in ac frequency (3.39 K for ν = 37.7 Hz and 3.71 K for ν = 9037 Hz). This positive shift in the peak temperature with increasing frequency reveals glassy or superparamagnetic state formation in $Pr_2Ni_{0.95}Si_{2.95}$.

In a typical glassy system, the frequency dependence of peak shift is generally classified by the parameter²,

$$\delta T_f = \frac{\Delta T_f}{T_f \Delta \log_{10} \nu} \tag{6}$$

The observed values of δT_f for canonical spin glasses are found to be $\sim 10^{-3}$. However, in case of different spin cluster glass compound, δT_f is of the order of 10^{-2} and for several reported superparamagnetic systems $\delta T_f \sim 10^{-1}$. We have found $\delta T_f = 0.031$ for $\Pr_2 \text{Ni}_{0.95} \text{Si}_{2.95}$, which is in the range of that for different reported cluster glass systems. Thus, frequency dependent ac susceptibility measurement signifies glassy state formation in $\Pr_2 \text{Ni}_{0.95} \text{Si}_{2.95}$ with spin freezing temperature, $T_f = 3.3$ K.

The frequency dependence of freezing temperature (T_f) was analyzed using the concepts of the dynamic scaling theory that predicts the critical power law of the form^{2,22},

$$\tau = \tau_0 \left(\frac{T_f - T_{SG}}{T_{SG}} \right)^{-z\nu'} \tag{7}$$

where τ (=1/ ν) is the relaxation time corresponding to the excitation frequency, τ_0 is the characteristic relaxation time of single spin flip, T_{SG} is the spin glass temperature at zero frequency and the dynamic critical exponent is $z\nu'$ [where, ν' is the critical exponent of correlation length, $\xi = (T_f/T_{SG}-1)^{-\nu'}$ and the dynamical scaling relates τ to ξ as $\tau \sim \xi^z$]. For a spin glass system, $z\nu'$ typically lies between 4 and 12. The value of τ_0 for canonical spin glasses fall in the characteristic range $\sim 10^{-12}-10^{-13}\,\mathrm{s}^{23}$, whereas, for a spin cluster glass system τ_0 value typically founds to be in the range $\sim 10^{-4}-10^{-11}\,\mathrm{s}^{24}$. Relatively higher values of τ_0 correspond to superparamagnetic state formation. The linear fit of log – log plot of τ as a function of reduced temperature, t, yields $\tau_0 \simeq 10^{-8}\,\mathrm{s}$ and $z\nu' = 4.02$ for $\mathrm{Pr}_2\mathrm{Ni}_{0.95}\mathrm{Si}_{2.95}$ [inset (I) of Fig. 8(a)]. Thus spin freezing behaviour in this compound can be described by cluster glass state formation, where rather than individual spins, clusters of spins take part in the freezing process.

In glassy systems, spin dynamics near the freezing temperature can be modeled by another dynamical scaling law, known as the empirical Vogel-Fulcher relation^{2,25}, described as,

$$\nu = \nu_0 \exp\left(-\frac{E_a}{K_B(T_f - T_0)}\right) \tag{8}$$

where the fitting parameters ν_0 , E_a and T_0 are known as characteristic frequency, activation energy and the Vogel-Fulcher temperature, respectively. For canonical spin glasses the ratio, $\frac{E_a}{K_B}/T_0$ generally found to be close to 1, and the relatively larger value corresponds to while for spin cluster glass state formation. The best estimated values obtained for $\Pr_2 \text{Ni}_{0.95} \text{Si}_{2.95}$ are $\frac{E_a}{K_B} = 8.31 \, \text{K}$ and $T_0 = 2.81 \, \text{K}$ [inset (II) of Fig. 8(a)]. This result also indicates cluster glass state formation for this compound. Thus on the basis of all the results obtained from dynamical scaling laws of ac susceptibility data, it is argued that the newly synthesized compound $\Pr_2 \text{Ni}_{0.95} \text{Si}_{2.95}$ exhibits spin cluster glass behaviour below its freezing temperature (3.3 K).

The most interesting part of the ac susceptibility measurement for $Pr_2Ni_{0.95}Si_{2.95}$ is the observation of a distinct, additional peak (say, at $T=T^*$) slightly below the spin freezing temperature, T_f . The observation of the second peak at low temperature might suggest the presence of an additional magnetic phase in this compound. Earlier, we have reported that the magnetic ground state of isostructural Er_2NiSi_3 compound exhibits two different antiferromagnetically ordered phases in addition to the presence of a spin glass phase⁵. Isostructural compound $Sm_2Ni_{0.87}Si_{2.87}$ exhibits magnetically frustrated cluster glass behaviour in the presence of macroscopically different competing magnetic phases¹³. It may be noted here that the magnetic phase inhomogeneity in these materials arises due to the local environmental variation among the rare-earth ions mediated by non-magnetic ions, although the compound is considered to be crystallographically single phase as determined from XRD and neutron diffraction measurements. This type of inhomogeneity produces random magnetic anisotropy (RMA) in these material, which is responsible for different magnetic phases coexistence with limited correlation length. Depending on the correlation length these type of systems exhibit spatially limited magnetic ordering coupled with glassy magnetic phases. Accordingly, it appears that the two peaks in ac susceptibility measurements of $Pr_2Ni_{0.95}Si_{2.95}$ might arise due to the formation of two different magnetic phases in crystallographically single phase material.

From Fig. 8, one can notice that similar to the frequency dependent high temperature peak (T_f) shift due to the glassy behaviour, the low temperature peak also exhibit a frequency dependent shift in temperature that apparently exclude the possibility of its origin due to long range order. However, surprisingly, the frequency dependence of the low temperature peak appear to be in the reverse direction than that expected in case of glassy transitions. This is a highly unusual behaviour, and only a very few oxide compounds have been reported to exhibit such behaviour in literatures^{26–29}. However, it may be noted here that so far, only one work has been reported in the literature with bidirectional frequency dependence, that too on an oxide compound NaNiO₂ which follows superexchange mechanism²⁶. In contrast, $Pr_2Ni_{0.95}Si_{2.95}$ is an intermetallic compound, where the magnetic exchange interaction is of RKKY-type. Furthermore, despite the superficial similarity between the phenomenon reported in NaNiO₂ and in our work on $Pr_2Ni_{0.95}Si_{2.95}$, there are significant differences. While in the oxide compound, the spin glass state has the freezing temperature lower than the temperature where the reverse

frequency shift is observed, in our case the trend is just the opposite. It was first reported in NaNiO $_2$, that exhibit a spin glass behaviour close to 3 K and undergoes antiferromagnetic ordering below 19.5 K (T_N) 26 . However, slightly above the T_N , the ac susceptibility measurement exhibit an additional peak around 24 K, whose frequency dependence is quite opposite to that observed glassy behaviour around 3 K. The muon decay asymmetry measurement in the temperature range 19.5–24 K could be modeled with two exponential components for NaNiO $_2$, one having much faster relaxing rate than the other and also varying differently with temperature. Since the amplitude of the faster relaxing component decreases with increasing temperature, it was suggested that the magnetic precursor effect to the antiferromagnetic order at 19.5 K persists up to 24 K, with the gradual decrease of relative volume fraction of the slowly fluctuating magnetic cluster sizes. It has been argued that this temperature dependent change in volume fraction of these magnetic clusters of different relaxation times may be related to the apparently unconventional peak-shift in the reverse direction. All the subsequent observations of such reverse peak shift in ac susceptibility measurements primarily used the same argument. Similar argument may hold good in our case of $Pr_2Ni_{0.95}Si_{2.95}$ as well.

However, there may be another mechanism that results in such reverse peak shift in ac susceptibility. The short range magnetic order due to the coalescing of magnetic spins takes place at temperature that is reflected in the peak in ac susceptibility. For a very small sizes of the clusters, the magnetic spins in a cluster favor parallel alignment along the externally applied magnetic field. As the external magnetic field strength decreases, the clustering process tends to shift towards lower temperature. Similarly, for a particular ac field, as the applied ac frequency increases, the average field in a particular direction over a fixed period of time would also decrease and therefore would have a similar effect as that of reduced field. Thus, the coalescing process of the magnetic clusters would gradually shift to lower temperature with increasing frequency, as is the phenomenon observed in our case of Pr₂Ni_{0.95}Si_{2.95}. However, in such cases, very low strength of the applied ac field strength (4 Oe) suggest that, both the magnetic moment as well as sizes of the clusters have to be significantly small so that even such small ac field can have observable impact. It may be mentioned here that, we have earlier reported that the coherence length of the magnetically ordered phase of Er₂NiSi₃ at 0.8T_N ~ 143 Å (~35 unit cells) and tend to saturate at low temperature with the value of 250 Å (~60 unit cells)⁵. The long range magnetic ordering could not be seen in Ho₂Ni_{0.95}Si_{2.95} as the coherence length at 1.5 K is about 35 Å (~8 unit cells), although magnetization and heat capacity studies reveal magnetic clusters appear to form below 3.6 K⁶. The temperature dependence of ac susceptibility peak at 3.6 K remain insensitive to change in frequency, which further reveals magnetic clusters in Ho₂Ni_{0.95}Si_{2.95} even do not exhibit inter-cluster correlations, therefore no cluster-glass phenomenon could be seen either. On the other hand, in Sm₂Ni_{0.87}Si_{2.87} the ferromagnetic clusters are correlated to each other and give rise to cluster glass state formation below $6.6\,\mathrm{K}^{13}$. Since the ground state of $R_2\mathrm{NiSi}_3$ series of compounds have been earlier shown to have comprised of multiple magnetic phase, e.g., different antiferromagnetic and glassy phases in Er₂NiSi₃, we propose that magnetic ground state of Pr₂Ni_{0.95}Si_{2.95} consists of at least two magnetic phases, a magnetic glassy phase coupled with of non-correlated small magnetic clusters. The origin of the coexistence of different magnetic phases lies in the crystal structure of the compound. In $Pr_2Ni_{0.95}Si_{2.95}$, as $c/a \simeq 1.05$, the nearest-neighbour exchange interactions of the compound of the compound. tion (J_{NN}) and next-nearest-neighbour exchange interaction (J_{NNN}) are of comparable strength. As in these system, exchange interaction is RKKY type and the strength (J_{ex}) of which depends on the interatomic distance (d)as, $J_{ex} \propto 1/d^3$, the third-nearest-neighbour exchange interaction strength is relatively insignificant. The dc magnetic measurement results further suggest that J_{NN} and J_{NNN} are of opposite sign, that causes a strong frustration in the system. Additionally, Ni and Si ions are inhomogeneously distributed between the hexagonal layers comprising of Pr ions and is responsible for the variation in the local electronic environment among the Pr-ions. In the presence of such strong frustration and crystallographic disorder, the magnetic ground state of Pr₂Ni_{0.95}Si_{2.95} founds to be magnetically inhomogeneous. We also believe that the size of the magnetic clusters in Pr₂Ni_{0.95}Si_{2.95} are of even further reduced length scale (smaller than 8 unit cells). Since the magnetic moment of Pr is much smaller ($\mu_{\rm Pr} \ll \mu_{\rm Ho}$, $\mu_{\rm Er}$), the effect of frequency dependence of ac magnetic field may produce an effect described as above. Additionally, in case of ${\rm Er_2NiSi_3}$, we have also shown that, for the antiferromagnetically ordered phase the propagation vectors (k) are quite small, leading to a very large magnetic full Bloch wave of about 6-10 unit cells. If the cluster size in Pr₂Ni_{0.95}Si_{2.95} is smaller than the Bloch wave length, the effective moments in the cluster act ferromagnetic like and as a result the coalescing temperature of the magnetic clusters will decrease with the increase of frequency, i.e., the decrease of effective field value. This type of substantial confinement of antiferromagnetic spin waves are reported to being sensitive as ferromagnetic order in Lanthanide metals. It may be mentioned here that the frequency dependent variation of RKKY interactions has already been investigated theoretically earlier.

While a full microscopic modeling of the observed reverse peak shift of the ac susceptibilities is beyond the scope of the present work, we now provide a simple phenomenological model that is based on the above-mentioned physical heuristic arguments and qualitatively reproduce the general experimental features. In fact, by using this model we argue that the ω -dependent overall vertical shift observed in the plots of the susceptibilities in Fig. 8 occurs even for a single isolated spin in an external magnetic field, where as the horizontal reverse shift of one of the peaks in the same plots is essentially consequences of interactions. Consider first a single spin S in an external magnetic field h(t). The simplest dynamical equation for S in the overdamped limit reads

$$\frac{dS}{dt} = -\Gamma S + \Gamma h(t),\tag{9}$$

with Γ , a constant, is the damping coefficient. This yields for the frequency ω dependent susceptibility $\chi(\omega)$ as³⁰

$$\chi(\omega) = \frac{\Gamma}{-i\omega + \Gamma},\tag{10}$$

that is in general a complex function of ω . The real part $\chi'(\omega)$ of $\chi(\omega)$ is thus given by

$$\chi'(\omega) = \frac{\Gamma^2}{\omega^2 + \Gamma^2},\tag{11}$$

where as, the imaginary part $\chi''(\omega)$ is

$$\chi''(\omega) = \frac{\omega\Gamma}{\omega^2 + \Gamma^2}.$$
 (12)

In the limit of large damping (or, low ω), such that $\omega/\Gamma \ll 1$, the leading order ω -dependences of $\chi'(\omega)$ and $\chi''(\omega)$ reads

$$\chi'(\omega) = 1 - \frac{\omega^2}{\Gamma^2} + O(\omega^4),\tag{13}$$

that decreases as ω increases for large damping. In contrast,

$$\chi''(\omega) = \frac{\omega}{\Gamma} + O(\omega^3) \tag{14}$$

rises with ω for large damping. Equations (13) and (14) then qualitatively reproduce the decrease and increase in $\chi'(\omega)$ and $\chi''(\omega)$ with ω as seen in Fig. 8(a,b), respectively. We thus note that a single spin in an external magnetic field is sufficient to reproduce this behaviour.

Any peak in the susceptibilities is usually associated with transitions that require interactions between the microscopic degrees of freedom (here spins). Instead of constructing a microscopic theory for interacting degrees of freedom for the present system, we approach it phenomenologically by taking cue from the experimental results and the physical picture drawn above, largely in the spirit of the well-known Curie-Weiss mean-field theory of ferromagnetism³¹. We start by assuming a temperature (T) dependent form for the *effective* damping $\Gamma_e(T)$:

$$\Gamma_e(T) = \Gamma + A(T - T^*)^2 + B(T - T_c)^2,$$
(15)

where A>0 and B>0 are phenomenological constants, T^* and T_c are the two temperatures corresponding to the two peaks observed in Fig. 8 32 (A more rigorous analysis would involve allowing Γ_c to have *both* real and imaginary parts as functions of ω , as will be enforced by the Kramer-Kronig relations 30 . We ignore such complications here). We also assume $T^* < T_c$, i.e., the peak at $T = T^*$ corresponds to the left peak in Fig. 8 that display reverse shift as ω rises. As discussed above, T^* is the ordering temperature of an ordering transition that results from a competition between an ordering frequency-dependent external magnetic $h(\omega)$ and thermal energy k_BT (k_B is the Boltzmann factor). We set

$$\langle h \rangle_t^2 = k_B T^*, \tag{16}$$

that yields T^* , where the subscript t refers to the *temporal averaging h over a finite time t*. For a ω -dependent h, $\langle h \rangle_t$ clearly decreases as ω increases: $\langle h \rangle_t$ should be a monotonically decreasing function of ω . While the precise ω -dependence of $\langle h \rangle_t$ should depend upon the functional form of $h(\omega)$, we assume $\langle h \rangle_t \sim C/\omega$, where C is another phenomenological constant. This yields for the transition temperature $T^* \sim C/(\omega^2 k_B)$ that clearly decreases with ω , resulting into a reverse shift of the peak associated with T^* (We ignore the issue of the singularity in T^* as $\omega \to 0$. This is an artifact of the simple ω -dependence of $\langle h \rangle_t$ chosen here. A more accurate knowledge of the ω -dependence of T^* will rectify this and quantitatively change the form of T^* as a function of ω . Nonetheless, the general trend should remain unchanged from here). This is consistent with the observed reverse shift with a rise in ω in the plots given in Fig. 8.

To further confirm that the glassy state is originating from the magnetic clusters, we have performed magnetic relaxation behaviour at different temperatures (below T_f) and analyzed the data by model proposed by Ulrich *et al.*³³. This model applicable for a system consisting of interacting magnetic particles, suggest the rate of change of normalized remanent magnetization, $W(t) = -(d/dt)[\ln m(t)] \ (m(t) = M(t)/M(t=0))$, decays following the law,

$$W(t) = At^{-n}, \ t \ge t_0 \tag{17}$$

where A is a constant prefactor, n is an density dependent exponent of temperature and t_0 is crossover time after which the model is valid. The decay of W(t) and the values of n obtained for two different temperatures are shown in Fig. 9. At T = 3 K, which is in the vicinity of T_p n is close to 1 indicating quite strong intercluster interaction. Since n is a parameter which reflects the strength of magnetic interactions, the change in the value of n with temperature further confirm the growth of intercluster strength as freezing temperature is approached. This type of behaviour also confirm freezing of spin cluster rather than individual spin freezing.

Different types of glassy system are known to exhibit non-equilibrium dynamical behaviour below their freezing temperature. The systems remains in a non-equilibrium state and it exhibits slow magnetic relaxation dynamics over decades of time. In ZFC protocol, the magnetic relaxation behaviour have been measured by cooling the sample to a measurement temperature ($T < T_f$) in zero magnetic field. After the lapse of certain time (t_w) at the required temperature, small amount of external magnetic field ($\mu_0 H < k_B T_f$) is applied and time dependence of magnetization [M(t)] is recorded. As seen from Fig. 10(a), the experimentally observed magnetic relaxation behaviour can be perfectly demonstrated by standard stretched exponential function of the form^{2,34},

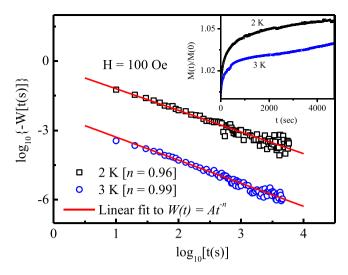


Figure 9. The log-log plot magnetic relaxation rate of $Pr_2Ni_{0.95}Si_{2.95}$ vs time at different temperatures. Inset shows the the corresponding relaxations of normalized ZFC magnetization in 100 Oe field. The straight lines represent the linear fit to Eq. 17 and the slopes of the fitted straight lines are the values of exponent n.

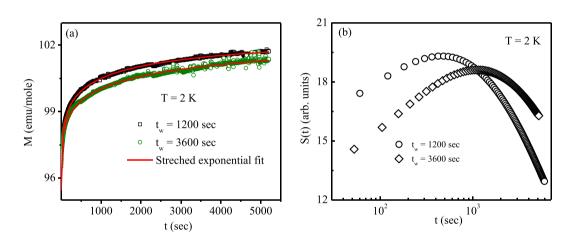


Figure 10. (a) Magnetic relaxation behaviours under ZFC protocol at 2 K along with stretched exponential fit [Eq. 18] and (b) the corresponding relaxation rate S(t) for different wait times, $t_w = 1200$ sec and 3600 sec for $Pr_2Ni_{0.95}Si_{2.95}$.

$$M(t) = M_0 \pm M_g \exp\left[-\left(\frac{t}{\tau}\right)^{\beta}\right]$$
(18)

where M_0 is the associated intrinsic magnetization of the system, M_g is related to magnetization fraction correspond to glassy magnetic phase, τ is called the relaxation time constant and β is known as stretching exponent. The value of β depends on the nature of energy barriers involves in the relaxation process. Since typical spin glass systems are classified with a distribution of energy scales, β values remains in the range $1 > \beta > 0$.

As seen from Table 2, the obtained value of τ increases with increasing t_w , indicating a stiffening of the spin relaxation with time. This clearly indicates the aging process in the system and also the signature of non-equilibrium dynamical behaviour. An inflection point occurs in the M(t) curve that shifts to higher observation time with increasing t_w . The inflection point is best visualized as a peak in the magnetic viscosity curve, defined as,

$$S(t) = (1/H)\frac{dM(t)}{d(\log t)} \tag{19}$$

The peak in S(t) curve shifts to higher observation time with increasing the wait time, t_w , as shown in Fig. 10(b). This type of aging phenomena establish non equilibrium dynamical domain growth in $Pr_2Ni_{0.95}Si_{2.95}$.

t_w (sec)	M ₀ (emu/mole)	M _g (emu/mole)	au (sec)	β
1200	102.58 (1)	7.15 (4)	520 (6)	0.32
3600	102.6 (1)	7.88 (1)	1163 (29)	0.32

Table 2. Fitted parameters of the magnetic relaxation data of $Pr_2Ni_{0.95}Si_{2.95}$ at 2 K for different wait times using Eq. 18.

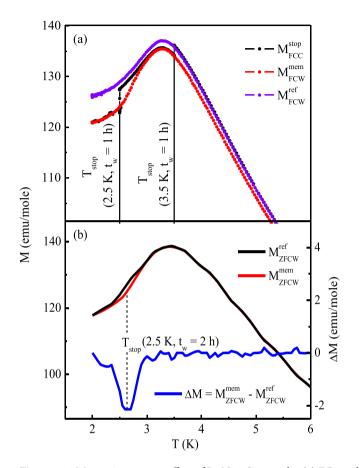


Figure 11. Magnetic memory effect of $Pr_2Ni_{0.95}Si_{2.95}$ under (a) FC condition and (b) ZFC condition for 100 Oe applied field.

Magnetic memory effect for the compound has been measured in the thermal variation of the magnetization under both FC and ZFC process at an applied magnetic field value of 100 Oe. The whole measurement process has been carried out with constant temperature sweep rate, 1 K/min. In FC process, the sample was initially cooled down to the temperature 2 K, from the paramagnetic region (50 K) in the presence of magnetic field. During this cooling process the sample was "halted" at some stopping temperatures, $T_{\rm stop} = 3.5$ K and 2.5 K of duration $t_w = 1$ h. After reaching each $T_{\rm stop}$, the magnetic field was removed and after the time lapse of t_w the same magnetic field was reapplied followed by resuming cooling process. This curve is defined as M_{FCC}^{stop} , as seen in the Fig. 11(a). The magnetization (M_{FCW}^{mem}) was then measured in heating mode from 2 K to 50 K without any halt. It is clear from the Fig. 11(a) that, M_{FCW}^{mem} shows an upturn beyond 2.5 K, *i.e.*, it is trying to follow its previous history exhibiting magnetic memory effect. However, no such memory effect is observed in M_{FCW}^{mem} curve beyond $T_{\rm stop} = 3.5$ K, which is slightly higher that the spin freezing temperature for this system. This type of magnetic memory effect has also been observed in ZFC process [Fig. 11(b)]. ZFC memory effect is a more sensitive phenomena for spin glass systems and is forbidden in other types of non equilibrium systems. During this process, the sample was initially cooled down to the lowest temperature (2 K) in zero magnetic field with intermediate stop at $T_{\rm stop} = 2.5$ K. The magnetization (M_{ZFCW}^{mem}) measured during heating process when subtracted from conventional ZFC magnetization (M_{ZFCW}^{mem}), the difference curve ($\Delta M = M_{ZFCW}^{mem} - M_{ZFCW}^{ref}$) clearly exhibits a memory dip further confirming the spin glass state formation for this compound \$5.36.

In a magnetic system with random magnetic anisotropy magnetic memory effect is best described by hierarchical model^{37,38} which favours multivalley spin structure on the free energy landscape, rather than droplet model^{39,40} that favours only one spin configuration at a particular temperature. Thus, symmetric relaxation behaviour is expected with respect to heating and cooling in droplet model while that should be asymmetric

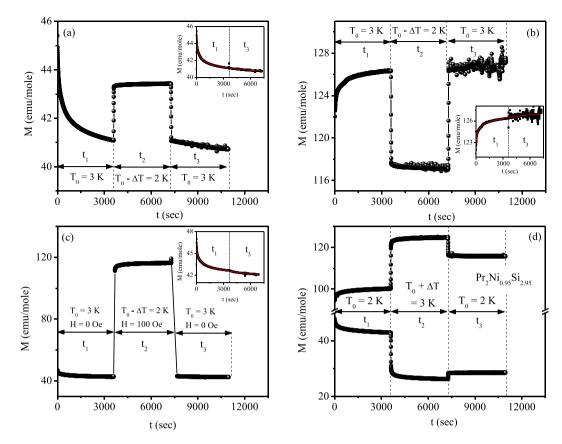


Figure 12. Magnetic relaxation of $Pr_2Ni_{0.95}Si_{2.95}$ at 3 K for H = 100 Oe with temporary cooling to 2 K for the (a) FC method and (b) ZFC method. (c) Magnetic relaxation for the FC protocol at 3 K with opposite field changes during temporary cooling to 2 K. The insets show the relaxation data vs the total time spent at 3 K along with the fit (solid red line) using stretched exponential function [Eq. 18]. (d) Magnetic relaxation at 2 K with temporary heating to 3 K in both the ZFC and FC methods for 100 Oe applied magnetic field.

in $Pr_2Ni_{0.95}Si_{2.95}$ system. To experimentally prove this, the relaxation behaviour is measured with both temporary cooling and heating using the protocol proposed by Sun $et~al.^{35}$. Figure 12(a,b) display isothermal magnetic relaxation in FC and ZFC protocols, respectively, at $T_0=3$ K measured in 100 Oe with temporary cooling at $T_0-\Delta T=2$ K. Initially, M(t) was recorded for time, $t_1=1$ h. At the end of t_1 , the temperature was quenched to 2 K and after time scale $t_2=1$ h, the temperature was raised back to 3 K. Finally M(t) was measured at 3 K for $t_3=1$ h. Figure $t_2(c)$ shows the magnetic relaxations at 3 K with switching on and off the magnetic field in consecutive time scale. M(t) was measured with 100 Oe magnetic field during t_2 , while M(t) were measured at zero field during t_1 and t_3 . As seen from the figures, when the system is heated back to t_3 0, the magnetizations are exactly retrieved to the same level it was before the temporary cooling processes. The M(t) during t_3 is continuous to that during t_1 and can be well described by single stretched exponential function of the form of Eq. 18. Thus, temporary cooling has no impact on the observed magnetic memory behaviour during relaxation process. However, the relaxation curve during t_3 is totally different of that during t_1 when the system is temporarily heated during the time interval t_2 in both the ZFC and FC processes, as seen from Fig. 12(d). Thus relaxation behaviour cannot restore its previous history when it is temporarily heated to t_3 0. This type of contradictory response upon cooling and heating is in accordance with the hierarchical model.

In conclusion, we report here the successful synthesis of a new ternary intermetallic compound $Pr_2Ni_{0.95}Si_{2.95}$ that forms in single phase only by creating vacancies in Ni/Si site. The compound undergoes spin freezing behaviour below 3.3 K, characterized through meticulous studies on dc magnetization, heat capacity, ac magnetization & related dynamic scaling, several non-equilibrium dynamical behaviour. The primary interest in this material commence from the fact that $Pr_2Ni_{0.95}Si_{2.95}$ is the only intermetallic compound that exhibits bidirectional frequency dependence of dynamical susceptibility - a fact hitherto not emphasized so far. The observation of unusual frequency dependence of the additional peak below the freezing temperature has been attributed due to the magnetic phase separation in this compound. Due to the presence of competing magnetic exchange interactions and atomic disorder, the magnetic ground state of the compound found to be consisting of macroscopically different magnetic phases, a magnetic glassy phase coexisting with nanoscopic non-correlated small magnetic clusters. The spin dynamics of such clusters has been argued to be responsible for such reverse frequency shift. Our proposed phenomenological model also reproduces the qualitative features observed in the low temperature ac susceptibility data. A full-fledged microscopic theory would be needed to calculate the form Γ_ε that is used here in

Eq. (15). Such an attempt, if successfully carried out, would also provide information about the phenomenological constants *A*, *B* and *C* introduced in the model. This remains a challenging theoretical task.

Methods

The polycrystalline materials were synthesized by melting the calculated proper amount of constituent elements, viz., Pr, Ni and Si of high purity (>99.9%) in an arc furnace under inert (Ar) environment. Powder X-ray diffraction (XRD) measurements were carried out at different temperatures ($15 \, \text{K} \leq \text{T} \leq 300 \, \text{K}$) using Cu-K $_{\alpha}$ radiation on a TTRAX-III difractometer (M/s Rigaku, Japan). Structural characterization and the check of phase purity were performed by Rietveld refinement of XRD data using FULLPROF software package¹⁸. The scanning electron microscopy (SEM) measurements were carried out in the instrument EVO 18 (M/s Carl Zeiss, Germany) and the EDX measurements were performed in Element EDS system (M/s EDAX Inc., USA). Transmission electron microscopy (TEM) investigation was carried out using FEI, Tecnai G² F30, ST microscope operating at 300 kV equipped with a Gatan Orius SC1000B CCD camera. Specimen for TEM was prepared by crashing the sample into power, dispersed in ethanol and mounting on a carbon coated copper grid. The compositional analysis was performed by energy dispersive X-ray spectroscopy (EDS, M/s EDAX Inc., USA) attachment on the Tecnai G² F30. The dc magnetization was measured in a commercial SQUID VSM (M/s Quantum Design Inc., USA) & Ever Cool II VSM (M/s Quantum Design Inc., USA) and the ac susceptibility measurements were performed in a Ever Cool II VSM system (M/s Quantum Design Inc., USA). The heat capacity was measured by relaxation technique in a commercial PPMS system (M/s Quantum Design Inc., USA).

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Author Contributions

S.P. and C.M. conceived the idea for the work and directed the research. S.P. synthesized the sample, carried out the experiments and analysed the results. A.B. proposed the phenomenological model. R.R. and R.N.B. directed the ac susceptibility experiments. B.S. performed the TEM measurements and analysed the data. All authors discussed the results and wrote the manuscript.

Additional Information

Competing Interests: The authors declare no competing interests.

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